Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	
Glass	
Overall Length:	
0.205 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
0.107 inches	
Electrode Interna	ly-electrically Connected To Case:
Cathode	
Mounting Method	:
Terminal	
Features Provide	d:
Hermetically seale	d case
Semiconductor N	aterial:
Silicon	
Voltage Rating In	Volts Per Characteristic:
24.0 regulator vo	tage
Voltage Toleranc	e In Percent:
-5.0/+5.0	
Current Rating Po	er Characteristic:
10.50 milliamperes	all primaries horsepower metric and 40.00 milliamperes repetitive peak forward current
Power Rating Per	Characteristic:
1.0 watts small-sig	nal input power, common-collector preset
Maximum Operat	ng Tempurature Per Measurement Point:
175.0 degrees cels	ius ambient air
Test Data Docum	ent:
81349-mil-prf-1590	0 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes of	ommercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type Ar	d Quantity:
2 uninsulated wire	lead
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	
Mil-std (military S	tandard):
Mil-prf-15900 spec	